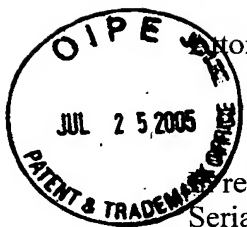


IFW



Attorney Docket No. 5308-291

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Re: Sheppard et al.

Confirmation No.: 6572

Serial No.: 10/758,871

Art Unit: 2811

Filed: January 16, 2004

For: NITRIDE-BASED TRANSISTORS WITH A PROTECTIVE LAYER AND
A LOW-DAMAGE RECESS AND METHODS OF FABRICATION
THEREOF

Date: July 21, 2005

Mail Stop Amendment
Commissioner for Patents
PO Box 1450
Alexandria, VA 22313-1450

SECOND PRELIMINARY AMENDMENT

Sir:

Please enter the following Preliminary Amendment before examining the present application.

Amendments to the Claims are reflected in the listing of claims, which begins on page 2 of this paper.

Remarks begin on page 10 of this paper.